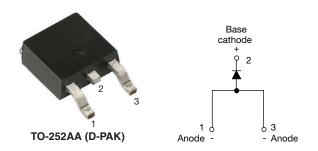


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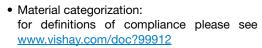
Surface Mount Fast Soft Recovery Rectifier Diode, 8 A



PRODUCT SUMMARY					
Package	TO-252AA (D-PAK)				
I _{F(AV)}	8 A				
V _R	1000 V, 1200 V				
V _F at I _F	1.3 V				
I _{FSM}	150 A				
t _{rr}	80 ns				
T _J max.	150 °C				
Diode variation	Single die				
Snap factor	0.6				

FEATURES

- · Glass passivated pellet chip junction
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C







HALOGEN FREE

APPLICATIONS

- Output rectification and freewheeling diode in inverters, choppers and converters
- Input rectifications where severe restrictions on conducted EMI should be met

DESCRIPTION

The VS-8EWF..S-M3 fast soft recovery rectifier series has been optimized for combined short reverse recovery time, low forward voltage drop and low leakage current.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL	CHARACTERISTICS VALUES UNITS							
I _{F(AV)}	Sinusoidal waveform	8	А					
V _{RRM}		1000/1200	V					
I _{FSM}		150	Α					
V _F	8 A, T _J = 25 °C	1.3	V					
t _{rr}	1 A, 100 A/µs	80	ns					
T _J	Range	-40 to +150	°C					

VOLTAGE RATINGS							
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA				
VS-8EWF10S-M3	1000	1100	4				
VS-8EWF12S-M3	1200	1300	4				

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum average forward current	I _{F(AV)}	T _C = 96 °C, 180° conduction half sine wave	8			
Maximum peak one cycle	l	10 ms sine pulse, rated V _{RRM} applied	125	Α		
non-repetitive surge current	I _{FSM}	10 ms sine pulse, no voltage reapplied	150			
Maximum I ² t for fusing	I ² t	10 ms sine pulse, rated V _{RRM} applied	78	A ² s		
Maximum I-t for fusing I-t		10 ms sine pulse, no voltage reapplied	110	A-5		
Maximum l²√t for fusing	I ² √t	t = 0.1 ms to 10 ms, no voltage reapplied	1100	A ² √s		

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ELECTRICAL SPECIFICATIONS							
PARAMETER SYMBOL TEST CONDITIONS VALUES UNITS							
Maximum forward voltage drop	V_{FM}	8 A, T _J = 25 °C		1.3	V		
Forward slope resistance	r _t	T _{.1} = 150 °C		25.6	mΩ		
Threshold voltage	V _{F(TO)}	1J = 150 C		0.93	V		
Maximum reverse leakage current	1	T _J = 25 °C	V - Poted V	0.1	mA		
Maximum reverse leakage current	I _{RM}	T _J = 150 °C	$V_R = Rated V_{RRM}$	4	l IIIA		

RECOVERY CHARACTERISTICS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	. •	
Reverse recovery time	t _{rr}	I _F at 8 A _{pk}	270	ns	I _{FM}	
Reverse recovery current	I _{rr}	25 A/μs	4.2	А	$\left \begin{array}{c} \downarrow \\ \downarrow $	
Reverse recovery charge	Q_{rr}	T _J = 25 °C	1	μC	di/ dt Q _{rr}	
Snap factor	S		0.6			

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction and storage temperature range	T _J , T _{Stg}		-40 to +150	°C		
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	2.5	°C/W		
Typical thermal resistance, junction to ambient (PCB mount)	R _{thJA} ⁽¹⁾		50	C/VV		
Approximate weight			1	g		
Approximate weight			0.03	oz.		
Marking device		Case style TO-252AA (D-PAK)	8EWF	-10S		
Marking device		Case style 10-232AA (D-PAR)	8EWF12S			

Note

⁽¹⁾ When mounted on 1" square (650 mm²) PCB of FR-4 or G-10 material 4 oz. (140 µm) copper 40 °C/W For recommended footprint and soldering techniques refer to application note #AN-994

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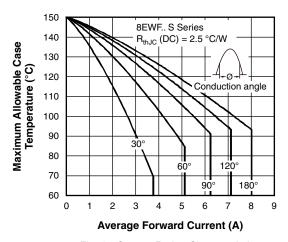


Fig. 1 - Current Rating Characteristics

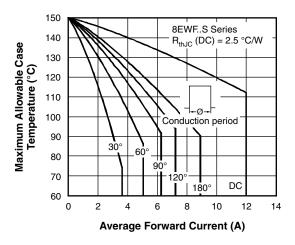


Fig. 2 - Current Rating Characteristics

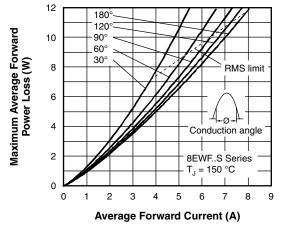


Fig. 3 - Forward Power Loss Characteristics

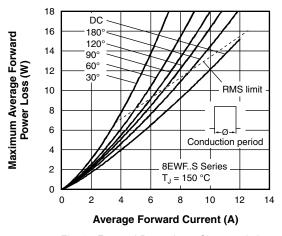


Fig. 4 - Forward Power Loss Characteristics

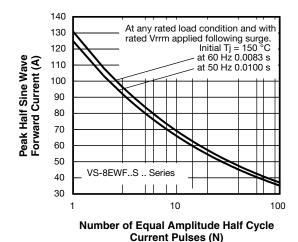


Fig. 5 - Maximum Non-Repetitive Surge Current

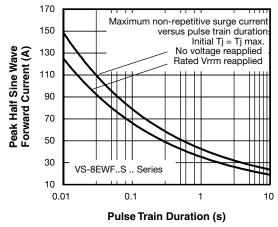


Fig. 6 - Maximum Non-Repetitive Surge Current



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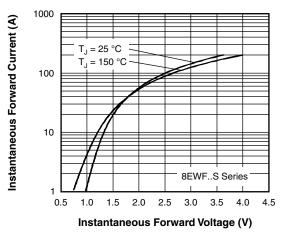


Fig. 7 - Forward Voltage Drop Characteristics

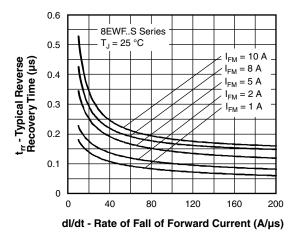


Fig. 8 - Recovery Time Characteristics, T_J = 25 °C

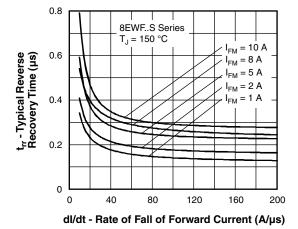
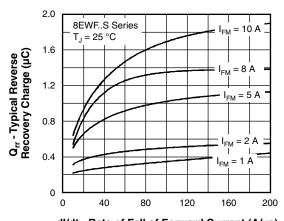


Fig. 9 - Recovery Time Characteristics, $T_J = 150 \, ^{\circ}\text{C}$



dl/dt - Rate of Fall of Forward Current (A/ μ s) Fig. 10 - Recovery Charge Characteristics, T_J = 25 °C

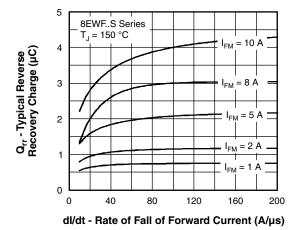


Fig. 11 - Recovery Charge Characteristics, T_J = 150 °C

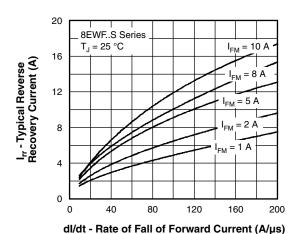


Fig. 12 - Recovery Current Characteristics, T_J = 25 °C

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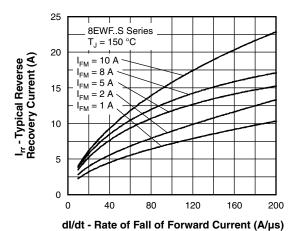


Fig. 13 - Recovery Current Characteristics, T_J = 150 °C

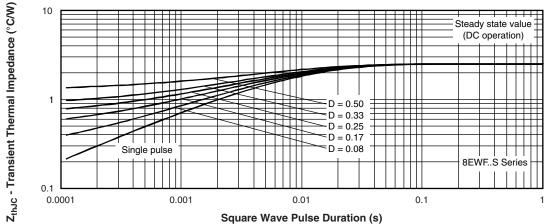
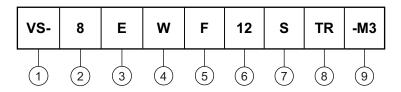


Fig. 14 - Thermal Impedance Z_{thJC} Characteristics

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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (8 = 8 A)

3 - Circuit configuration:

E = single diode

4 - Package:

W = D-PAK

5 - Type of silicon:

F = fast soft recovery rectifier

6 - Voltage code x 100 = V_{RRM} - 10 = 1000 V 12 = 1200 V

7 - S = surface mountable

8 - • TR = tape and reel

• TRR = tape and reel (right oriented)

• TRL = tape and reel (left oriented)

9 - Environmental digit:

-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-8EWF10S-M3	75	3000	Antistatic plastic tubes				
VS-8EWF10STR-M3	2000	2000	13" diameter reel				
VS-8EWF10STRL-M3	3000	3000	13" diameter reel				
VS-8EWF10STRR-M3	3000	3000	13" diameter reel				
VS-8EWF12S-M3	75	3000	Antistatic plastic tubes				
VS-8EWF12STR-M3	2000	2000	13" diameter reel				
VS-8EWF12STRL-M3	3000	3000	13" diameter reel				
VS-8EWF12STRR-M3	3000	3000	13" diameter reel				

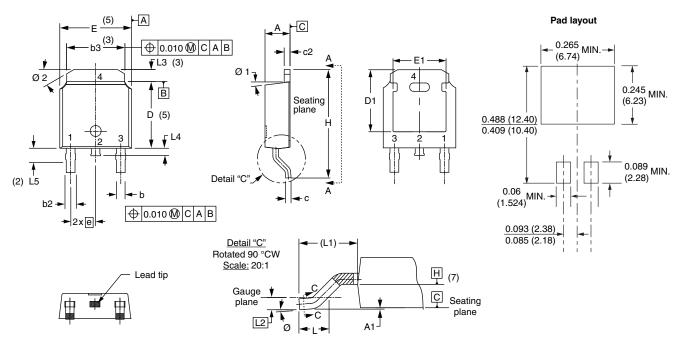
LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?95627</u>					
Part marking information	www.vishay.com/doc?95176				
Packaging information	www.vishay.com/doc?95033				
SPICE model	www.vishay.com/doc?95552				



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D-PAK (TO-252AA) "M"

DIMENSIONS in millimeters and inches



SYMBOL	MILLIN	IETERS	INCHES		NOTES	
STIVIDOL	MIN.	MAX.	MIN.	MAX.	NOTES	
Α	2.18	2.39	0.086	0.094		
A1	-	0.13	-	0.005		
b	0.64	0.89	0.025	0.035		
b2	0.76	1.14	0.030	0.045		
b3	4.95	5.46	0.195	0.215	3	
С	0.46	0.61	0.018	0.024		
c2	0.46	0.89	0.018	0.035		
D	5.97	6.22	0.235	0.245	5	
D1	5.21	-	0.205	-	3	
Е	6.35	6.73	0.250	0.265	5	
E1	4.32	-	0.170	-	3	

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
OTWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
е	2.29	BSC	0.090	BSC	
Н	9.40	10.41	0.370	0.410	
L	1.40	1.78	0.055	0.070	
L1	2.74 BSC		0.108	REF.	
L2	0.51	BSC	0.020 BSC		
L3	0.89	1.27	0.035	0.050	3
L4	-	1.02	-	0.040	
L5	1.14	1.52	0.045	0.060	2
Ø	0°	10°	0°	10°	
Ø1	0°	15°	0°	15°	
Ø2	25°	35°	25°	35°	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension uncontrolled in L5
- (3) Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad
- (4) Section C C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip
- (5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (6) Dimension b1 and c1 applied to base metal only
- (7) Datum A and B to be determined at datum plane H
- (8) Outline conforms to JEDEC® outline TO-252AA



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